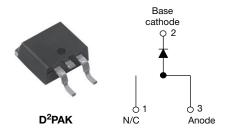


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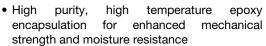
Schottky Rectifier, 16 A



| PRODUCT SUMMARY | | | | | | | |
|--------------------|-----------------|--|--|--|--|--|--|
| I _{F(AV)} | 16 A | | | | | | |
| V _R | 35 V/45 V | | | | | | |
| I _{RM} | 40 mA at 125 °C | | | | | | |

FEATURES

- 150 °C T_J operation
- High frequency operation
- · Low forward voltage drop





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Halogen-free according to IEC 61249-2-21 definition
- Compliant to RoHS directive 2002/95/EC
- AEC-Q101 qualified

DESCRIPTION

This VS-MBRB16... Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | | | |
|-----------------------------------|---------------------------------|-------------|-------|--|--|--|--|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | | | | | |
| I _{F(AV)} | Rectangular waveform | 16 | А | | | | | | |
| V _{RRM} | | 35/45 | V | | | | | | |
| I _{FSM} | t _p = 5 μs sine | 1800 | A | | | | | | |
| V _F | 16 Apk, T _J = 125 °C | 0.57 | V | | | | | | |
| T _J | | - 65 to 150 | °C | | | | | | |

| VOLTAGE RATINGS | | | | | | | | | |
|--------------------------------------|-----------|----------------|----------------|-------|--|--|--|--|--|
| PARAMETER | SYMBOL | VS-MBRB1635PbF | VS-MBRB1645PbF | UNITS | | | | | |
| Maximum DC reverse voltage | V_{R} | 35 | 45 | V | | | | | |
| Maximum working peak reverse voltage | V_{RWM} | 35 | 45 | V | | | | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | | |
|-----------------------------------|--------------------|--|---|-------|---|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONI | VALUES | UNITS | | | | | |
| Maximum average forward current | I _{F(AV)} | T _C = 134 °C, rated V _R | T _C = 134 °C, rated V _R | | | | | | |
| Non-repetitive peak surge current | I _{FSM} | Following any rated 5 μs sine or 3 μs rect. pulse load condition and with rated V _{RRM} applied | | 1800 | А | | | | |
| | | Surge applied at rated load single phase 60 Hz | 150 | | | | | | |
| Non-repetitive avalanche energy | E _{AS} | $T_J = 25 ^{\circ}\text{C}, I_{AS} = 3.6 \text{A}, L = 3.6 \text{A}$ | 24 | mJ | | | | | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to Frequency limited by T _J max | 3.6 | А | | | | | |

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VS-MBRB1635PbF, VS-MBRB1645PbF

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| ELECTRICAL SPECIFICATIONS | | | | | | | | |
|--------------------------------|--------------------------------|---|--|-------|----|--|--|--|
| PARAMETER | SYMBOL | TEST CO | VALUES | UNITS | | | | |
| Maximum forward voltage drop | V _{FM} ⁽¹⁾ | 16 A | T _J = 25 °C | 0.63 | ٧ | | | |
| Maximum forward voltage drop | VFM (1) | 10 A | T _J = 125 °C | 0.57 | | | | |
| Maximum instantaneous | I _{RM} ⁽¹⁾ | T _J = 25 °C | Rated DC voltage | 0.2 | mA | | | |
| reverse current | | T _J = 125 °C | hated DC voltage | 40 | | | | |
| Maximum junction capacitance | C _T | V _R = 5 V _{DC} (test signal range | $V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C | | | | | |
| Typical series inductance | L _S | Measured lead from top or | 8.0 | nΗ | | | | |
| Maximum voltage rate of change | dV/dt | Rated V _R | 10 000 | V/µs | | | | |

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | |
|--|---------|-------------------|--------------------------------------|-------------|------------------|--|--|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | |
| Maximum junction temperature | range | T_J | | - 65 to 150 | °C | | | |
| Maximum storage temperature range | | T_{Stg} | | - 65 to 175 | C | | | |
| Maximum thermal resistance, junction to case | | R _{thJC} | DC operation | 1.50 | °C/W | | | |
| Typical thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth and greased | 0.50 | C/VV | | | |
| Approximate weight | | | | 2 | g | | | |
| Approximate weight | | | | 0.07 | OZ. | | | |
| Mounting torque | | | | 6 (5) | kgf · cm | | | |
| Mounting torque - | maximum | | | 12 (10) | (lbf \cdot in) | | | |
| Marking device | | | Case style D ² PAK | MBRE | 31645 | | | |



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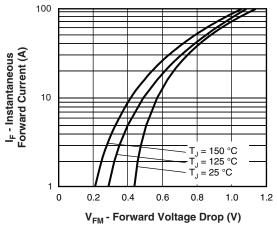


Fig. 1 - Maximum Forward Voltage Drop Characteristics

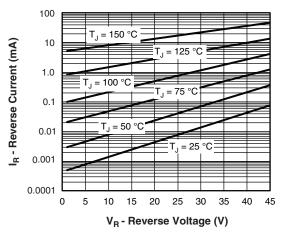


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

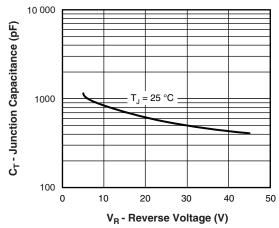


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

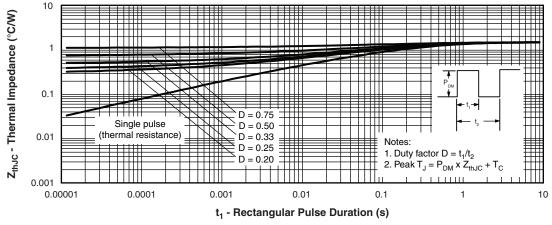


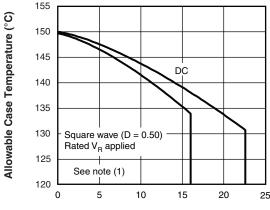
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

VS-MBRB1635PbF, VS-MBRB1645PbF

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I_{F(AV)} - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

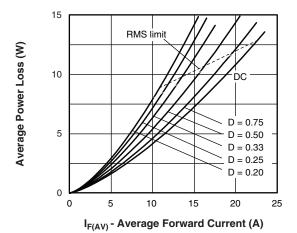
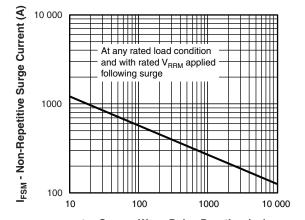


Fig. 6 - Forward Power Loss Characteristics



 t_p - Square Wave Pulse Duration (μ s) Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

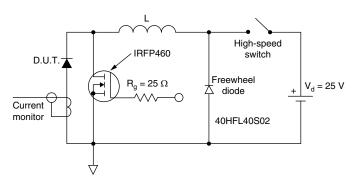


Fig. 8 - Unclamped Inductive Test Circuit

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \text{ applied} \\ \end{array}$



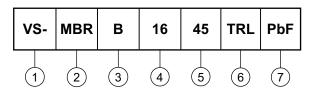
VS-MBRB1635PbF, VS-MBRB1645PbF

Schottky Rectifier, 16 A

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ORDERING INFORMATION TABLE

Device code



1 - HPP product suffix

2 - Essential part number

- B = Surface mount

Current rating (16 = 16 A)

- Voltage code = V_{RRM} 35 = 35 V 45 = 45 V

6 - • None = Tube (50 pieces)

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

7 - PbF = Lead (Pb)-free

| LINKS TO RELATED DOCUMENTS | | | | | | | |
|----------------------------|--------------------------|--|--|--|--|--|--|
| Dimensions | www.vishay.com/doc?95046 | | | | | | |
| Part marking information | www.vishay.com/doc?95054 | | | | | | |
| Packaging information | www.vishay.com/doc?95032 | | | | | | |
| SPICE model | www.vishay.com/doc?95407 | | | | | | |



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIMETERS | | INCHES | | NOTES | SYMBOL | MILLIM | ETERS | INC | HES | NOTES | |
|----------|-------------|-------|--------|-------|-------|---------|--------|-------|-------|-------|-------|------|
| STIVIBUL | MIN. | MAX. | MIN. | MAX. | NOTES | STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES | |
| Α | 4.06 | 4.83 | 0.160 | 0.190 | | | D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | | | Е | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | | E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | | е | 2.54 | BSC | 0.100 |) BSC | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | | Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | | L | 1.78 | 2.79 | 0.070 | 0.110 | |
| С | 0.38 | 0.74 | 0.015 | 0.029 | | | L1 | - | 1.65 | - | 0.066 | 3 |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | | L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | | L3 | 0.25 | BSC | 0.010 | BSC | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | | L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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